

## Features

- Glass passivated chip junction
- Low forward voltage drop
- Ultra-fast recovery time, high efficiency
- Moisture sensitivity: level 1, per J-STD-020



Package: DO-214AB (SMC)

## Applications

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer and telecommunication.

## Maximum Ratings (T<sub>A</sub>=25°C unless otherwise noted)

| Parameter   | Symbol             | GSMURS420        | Unit |
|---|--------------------|------------------|------|
| Maximum Repetitive Peak Reverse Voltage   | V <sub>RRM</sub>   | 200              | V    |
| Maximum RMS Voltage   | V <sub>RMS</sub>   | 140              | V    |
| Maximum DC Blocking Voltage   | V <sub>DC</sub>    | 200              | V    |
| Maximum Average Forward Rectified Current (See Figure 1.)                           | I <sub>F(AV)</sub> | 4                | A    |
| Peak Forward Surge Current (8.3ms Single Half Sine-Wave Superimposed On Rated Load) | I <sub>FSM</sub>   | 80               | A    |
| Typical Thermal Resistance <sup>1</sup>   | Junction-Ambient   | R <sub>θJA</sub> | 45   |
|   | Junction-Case      | R <sub>θJC</sub> | 8.5  |
| Operating Junction Temperature Range  | T <sub>J</sub>     | - 55 to + 150    | °C   |
| Storage Temperature Range   | T <sub>STG</sub>   | - 55 to + 150    |      |

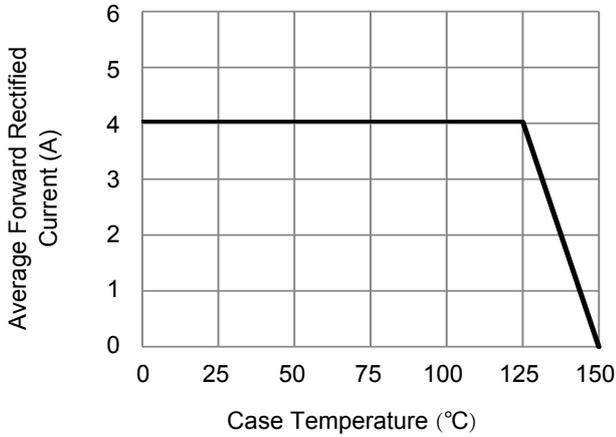
Note:

1. The thermal resistance from junction to ambient, case or lead, mounted on P.C.B with 30×30mm copper pads.

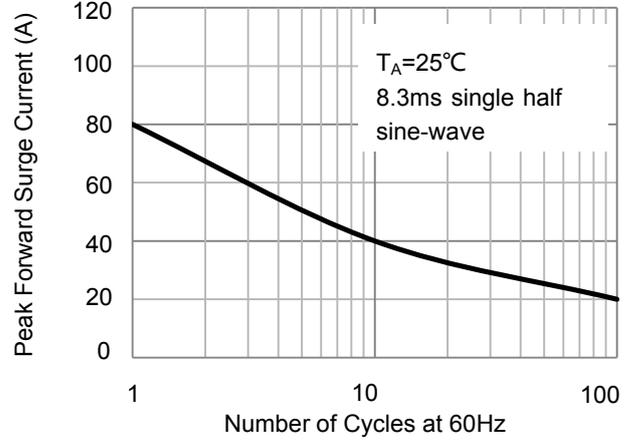
## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

| Parameter   | Symbol          | Test Conditions  | GSMURS420 | Unit |
|---|-----------------|--|-----------|------|
| Maximum Instantaneous Forward Voltage                   | V <sub>F</sub>  | I <sub>F</sub> =4A, T <sub>J</sub> =25°C                           | 0.89      | V    |
|   |                 | I <sub>F</sub> =4A, T <sub>J</sub> =150°C                          | 0.71      |      |
| Maximum DC Reverse Current at Rated DC Blocking Voltage | I <sub>R</sub>  | T <sub>J</sub> =25°C   | 5         | μA   |
|   |                 | T <sub>J</sub> =150°C  | 150       |      |
| Maximum Reverse Recovery Time                           | t <sub>rr</sub> | I <sub>F</sub> =0.5A, I <sub>R</sub> =1.0A, I <sub>rr</sub> =0.25A | 25        | ns   |
| Junction Capacitance                                    | C <sub>J</sub>  | 4.0V, 1MHz   | 65        | pF   |

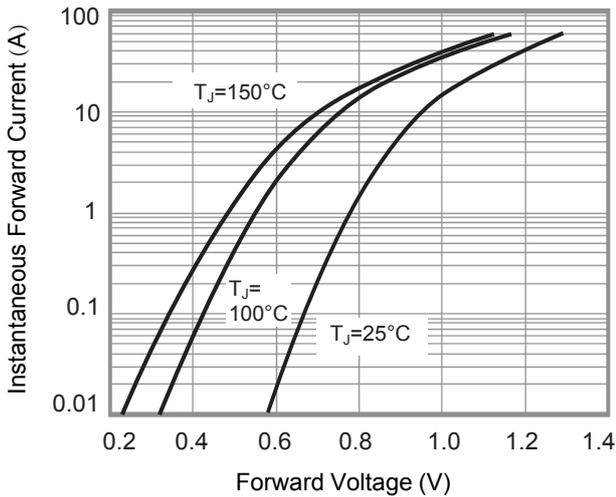
## Ratings and Characteristics Curves ( $T_A=25^\circ\text{C}$ unless otherwise noted)



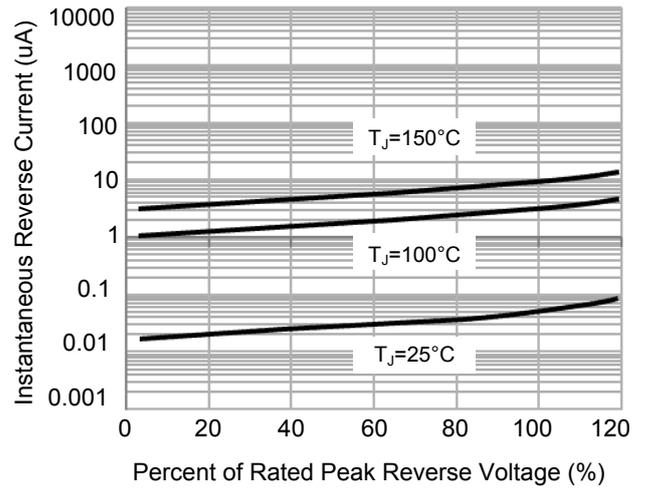
**Figure 1. Forward Current Derating Curve**



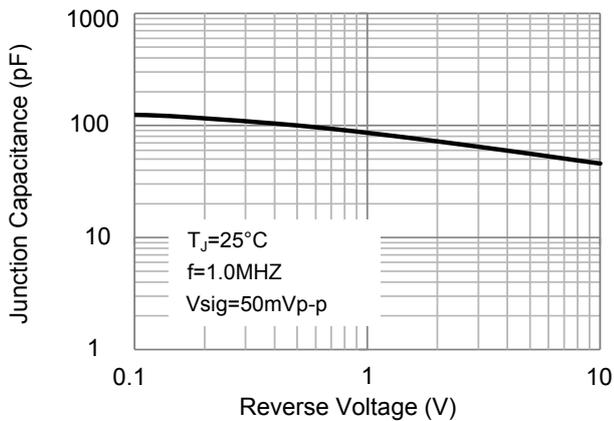
**Figure 2. Maximum Non-Repetitive Peak Forward Surge Current**



**Figure 3. Typical Instantaneous Forward Characteristics**

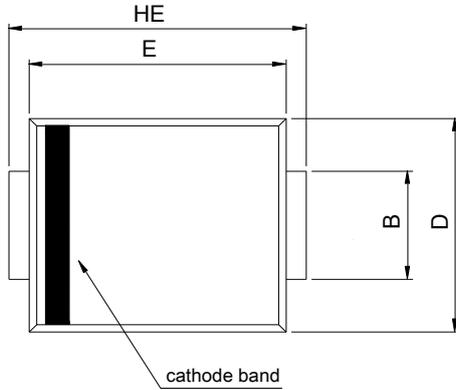


**Figure 4. Typical Reverse Leakage Characteristics**

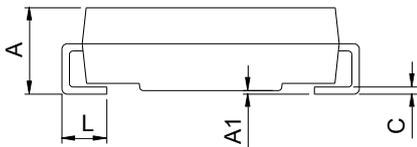


**Figure 5. Typical Junction Capacitance**

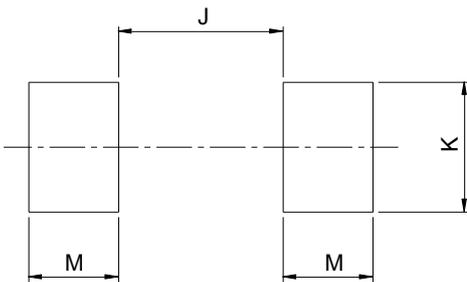
## Package Outline Dimensions DO-214AB (SMC)



| SMC (DO-214AB) |             |      |        |       |
|----------------|-------------|------|--------|-------|
| DIM            | Millimeters |      | Inches |       |
|                | Min.        | Max. | Min.   | Max.  |
| A              | 2.00        | 2.62 | 0.079  | 0.103 |
| A1             | 0.00        | 0.20 | 0.000  | 0.008 |
| B              | 2.90        | 3.20 | 0.114  | 0.126 |
| C              | 0.15        | 0.31 | 0.006  | 0.012 |
| D              | 5.58        | 6.22 | 0.220  | 0.245 |
| E              | 6.60        | 7.15 | 0.260  | 0.281 |
| HE             | 7.75        | 8.15 | 0.305  | 0.321 |
| L              | 0.76        | 1.60 | 0.030  | 0.063 |



## Recommended Pad Layout



| SMC Recommended Pad Layout (Reference ONLY) |             |      |        |       |
|---|-------------|------|--------|-------|
| DIM   | Millimeters |      | Inches |       |
|   | Min.        | Max. | Min.   | Max.  |
| J   | -           | 4.60 | -      | 0.181 |
| K   | 3.20        | -    | 0.126  | -     |
| M   | 2.00        | -    | 0.079  | -     |